



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Yasuhiko NOMURA et al.**

Serial No.: **09/666,553**

Filed: **September 21, 2000**

Group Art Unit: **2828**

Examiner: **Quyen Phan Leung**

P.T.O. Confirmation No.: **7592**

For: **SEMICONDUCTOR LIGHT EMITTING DEVICE**

**RESPONSE UNDER 37 C.F.R. §1.116**  
**- EXPEDITED RESPONSE -**  
**GROUP ART UNIT 2828**

**BOX AF**

Commissioner for Patents  
Washington, D.C. 20231

April 7, 2003

Sir:

In response to the Office Action dated November 5, 2002, the response due date extended to April 5, 2003 by a concurrently filed two-month Extension of Time, Applicants amend the above-identified application as follows:

**IN THE CLAIMS:**

**Please amend claims 1, 8, 11 and 17 as follows:**

1. (Amended) A semiconductor light emitting device comprising:

a nitride-based semiconductor layer including an emission layer; and

a dielectric film formed on the surface of said nitride-based semiconductor layer, wherein

the dielectric film contains a nitride formed directly on the surface of said nitride-based

semiconductor layer while containing an oxide formed on said nitride.

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